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### RAPID COMMUNICATION

## Study on thermoelectric performance by Na doping in nanostructured Mg<sub>1-x</sub>Na<sub>x</sub>Ag<sub>0.97</sub>Sb<sub>0.99</sub>



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#### Abstract

MgAg<sub>0.97</sub>Sb<sub>0.99</sub> was found to be potentially a new class of thermoelectric materials with *ZT* values above 1 in the temperature from 100 to 300 °C. In this report, we systematically studied the effect of Na doping in Mg,  $Mg_{1-x}Na_xAg_{0.97}Sb_{0.99}$ , on the thermoelectric properties and found Na was effective to increase the carrier concentration and power factor, especially below 180 °C, which led to higher *ZT* values, a better self-compatibility factor, and ultimately a higher output power at the optimal Na concentration of x=0.005-0.0075. © 2014 Elsevier Ltd. All rights reserved.

#### Introduction

Recent years have witnessed extensive studies on thermoelectric materials, which may play an important role in future energy conversion, production, management, and supply [1-5]. The efficiency of a thermoelectric material in a power generator or heat pump depends on the dimensionless thermoelectric figure of merit, *ZT*, defined

http://dx.doi.org/10.1016/j.nanoen.2014.11.027 2211-2855/© 2014 Elsevier Ltd. All rights reserved. as  $ZT = (S^2 \sigma / \kappa)T$ , where S,  $\sigma$ ,  $\kappa$ , and T are the Seebeck coefficient, electrical conductivity, thermal conductivity, and absolute temperature, respectively [6,7]. The numerator  $S^2 \sigma$  is called power factor (PF). Even though PF could be enhanced by engineering the electronic structure, and  $\kappa$  could be reduced by increasing the phonon scattering, it is very difficult to independently optimize them simultaneously since they are interrelated. The concept of "phonon-glass electron-crystal, PGEC" has been considered to be an effective way to decouple these interrelated quantities, but the experimental success is limited in only a few materials so far [8-10]. Recently, nanostructure approach was found to be the major technique for ZT enhancement by reducing the thermal conductivity and in some cases simultaneously improving the PF [11-14].

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Several classes of materials currently under investigation including PbTe, PbSe, their doped compounds [15-18], skutterudites [19-21], metal oxides [22,23], and half Heuslers [24-29] are suitable for the intermediate temperature range (300-500 °C) and high temperature range (500-1000 °C). However, for applications below 300 °C, there is no other material than Bi<sub>2</sub>Te<sub>3</sub> with ZT close to 1.4 [6,30,31] till recently when MgAgSb and its modified composition MgAg0.97Sb0.99 [32,33] were reported to have similar ZTs. MgAg<sub>0.97</sub>Sb<sub>0.99</sub> exhibited ZT of  $\sim\!0.7$  at room temperature and of 1.2 at 200 °C. A small amount of Ni has been used to alloy the Ag site and has resulted in enhancement of ZT to  $\sim$ 1 at 50 °C and  $\sim$ 1.4 at 180 °C. Herein, we report our effort on Na doping on Mg to make  $Mg_{1-x}Na_xAg_{0.97}Sb_{0.99}$  with x=0.005, 0.0075, and 0.01. Na has been considered as an ideal hole dopant with little effect on the other physical properties in many materials [34,35]. It was found that the enhancement of thermoelectric properties mainly comes from the increased PF, leading to higher ZTs, better self-compatibility factors, and output power.

#### Experimental details

#### Synthesis process

Based on the undoped phase-pure composition MgAg<sub>0.97</sub>Sb<sub>0.99</sub>, we studied substitution of Mg by Na by the two-step process [33]. First, elemental magnesium metal pieces (Mg, Sigma Aldrich, 99.9% metal basis), silver metal pieces (Ag, Sigma Aldrich, 99.9% metal basis), and sodium (Na, Sigma Aldrich, 99.9% metal basis) were weighed according to the stoichiometry of Mg<sub>1-x</sub>Na<sub>x</sub>Ag<sub>0.97</sub>Sb<sub>0.99</sub> with x=0, 0.005, 0.0075, and 0.01 and loaded in a stainless steel jar with stainless steel balls for mechanical alloying by a high energy ball mill (SPEX 8000D) for 10 h. After this step, we added antimony chunks (Sb, Sigma Aldrich, 99.8% metal basis) into the jar to further milling for 8 h. The final nanopowders were then loaded into a graphite die with an inner diameter of 12.7 mm, and consolidated by direct current (DC) hot pressing at  $\sim$  300 °C for 5 min.

#### Characterizations

X-ray diffraction spectra were collected on a PANalytical multipurpose diffractometer with an X'celerator detector (PANalytical X'Pert Pro). The microstructures, examined on a freshly broken surface, were investigated by a scanning electron microscope (SEM, JEOL 6330 F). Transmission electron microscope (TEM, JEOL 2010 F) was used to explore the details of grain size. The electrical resistivity ( $\rho$ ) and Seebeck coefficient (S) were measured using a four-point directcurrent switching method and the static temperature difference method, respectively, both of which were conducted on a commercial system (ULVAC ZEM-3). The thermal conductivity was obtained by measuring the thermal diffusivity (D) on a Nano flash apparatus (LFA 447, NETZSCH), specific heat ( $C_P$ ) on a DSC (404 C, NETZSCH), and volumetric density ( $\rho_{\Delta}$ ) by Archimedes method. The Hall measurement at room temperature was measured using the Physical Properties Measurement System (PPMS D060, Quantum Design).



Fig. 1 XRD patterns of  $Mg_{1-x}Na_xAg_{0.97}Sb_{0.99}$  (x=0, 0.005, 0.0075, and 0.01).

#### **Results and discussion**

Fig. 1 shows the XRD patterns of all samples. By comparing with the undoped pure phase  $MgAg_{0.97}Sb_{0.99}$ , no detectable impurity phases were found in  $Mg_{1-x}Na_xAg_{0.97}Sb_{0.99}$  (x=0.005, 0.0075, and 0.01).

To study the influence of Na doping on the TE properties of samples with compositions  $Mg_{1-x}$ materials, the Na<sub>x</sub>Ag<sub>0.97</sub>Sb<sub>0.99</sub> (x=0, 0.005, 0.0075, and 0.01) were prepared. As shown in Fig. 2(a), the electrical resistivity decreases with increasing Na content till x=0.0075, and the electrical resistivity of all the samples increases with temperature first to the maximum around 75-100 °C and then decreases. When the temperature is above 100 °C, the electrical resistivity decreases, which is consistent with the turning point in the Seebeck coefficient due to bipolar effect in Fig. 2 (b). Higher Na content leads to lower electrical resistivity due to the enhanced carrier concentration shown in Table 1. We compared the undoped sample with Na-doped samples of x=0.005, 0.0075, and 0.01 and found carrier concentration increases by 32.5%, 44.6%, and 43.2%, respectively. The carrier concentration  $(n_H)$  and Hall mobility  $(u_H)$ , which are also shown in Table 1, affect the electrical resistivity ( $\rho$ ) by the relationship  $1/\rho = n_H e u_H$ . Fig. 2(b) shows the temperature dependent Seebeck coefficient of all the Na doped samples. The Seebeck coefficient decreases with increasing Na content till x=0.0075, and increases with temperature from room temperature to 75-100 °C before decreases up to 275 °C. Combing the electrical resistivity and Seebeck coefficient, the PF of all Na doped samples are obtained as shown in Fig. 2(c). The increase in PF with temperature, especially below 100 °C, is pronounced as Na content increases. The highest PF among all the samples was found for x=0.0075. Na doping effectively optimizes carrier concentration and mobility, leading to lower electrical resistivity and the improvement of PF over the whole temperature range.

Fig. 3 shows the thermal transport properties of  $Mg_{1-x}Na_xAg_{0.97}Sb_{0.99}$  with x=0, 0.005, 0.0075, and 0.01. Specific heat  $(C_p)$  of  $MgAg_{0.97}Sb_{0.99}$ , shown in Fig. 3(a), is used for all compositions since replacing a tiny amount of Mg by Na will not increase the  $C_p$  at all due to the fact that Na is next to Mg, and diffusivity (D) of all samples

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